NSN 5961-01-226-8504

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-226-8504 **Inclosure Material:** Metal **Overall Length:** 1.742 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.684 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 repetitive peak off-state voltage and 600.0 repetitive peak reverse voltage and 720.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 63.00 amperes forward current, total rms horsepower metric and 920.00 amperes peak forward surge current absolute **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector universal **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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